



30V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	I _D max T _C = +25°C
30V	$4m\Omega@V_{GS} = 10V$	75A
	$7m\Omega@V_{GS} = 4.5V$	75A

Description

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$), yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Power Management Functions
- DC-DC Converters
- Backlighting

Features

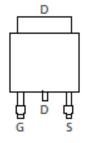
- Low On-Resistance
- Low Input Capacitance
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

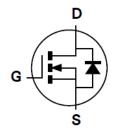
- Case:TO252
- Case Material: Molded Plastic, "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Matte Tin Finish.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.315 grams (Approximate)







Pin Out Top View



Equivalent Circuit

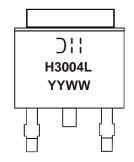
Ordering Information (Note 4)

Part Number	Case	Packaging
DMTH3004LK3-13	TO252	2500/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



Dili=Manufacturer's Marking
H3004L = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 15 = 2015)
WW = Week Code (01 to 53)



Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V_{DSS}	30	V		
Gate-Source Voltage			V_{GSS}	+20 -16	V
Continuous Dusin Compant (Nata C) V 40V	Steady State	$T_{C} = +25^{\circ}C$ $T_{C} = +70^{\circ}C$	I _D	75 75	А
Continuous Drain Current (Note 6) V _{GS} = 10V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	21 17	А
Pulsed Drain Current (380µs Pulse, Duty Cycle=1%)	I _{DM}	160	Α		
Maximum Continuous Body Diode Forward Current (Note 6)			Is	3	Α
Avalanche Current (Note 7) L=5mH			I _{AS}	10.7	Α
Avalanche Energy (Note 7) L=5mH			Eas	287	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		P_{D}	1.9	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady state	$R_{ heta JA}$	80	°C/W
Total Power Dissipation (Note 6)		P_{D}	3	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady state	$R_{ heta JA}$	50	°C/W
Thermal Resistance, Junction to Case		$R_{ heta JC}$	1.4	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +175	°C

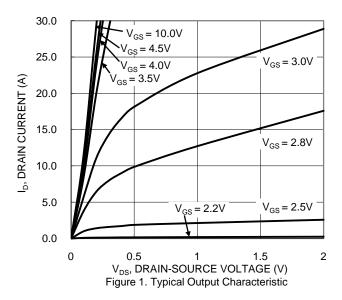
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

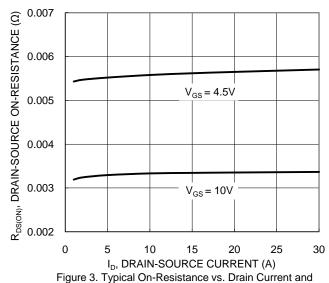
h							
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	30	-	-	V	$V_{GS} = 0V$, $I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	-	-	10	μΑ	$V_{DS} = 24V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	-	-	100	nA	$V_{GS} = +20V, V_{DS} = 0V$	
	1000			-100		$V_{GS} = -16V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)	1	1					
Gate Threshold Voltage	V _{GS(TH)}	1	-	3	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance	Decree 1	-	3.3	4	mΩ	$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Nesistance	R _{DS(ON)}	-	5.5	7	11122	$V_{GS} = 4.5V, I_{D} = 7A$	
Diode Forward Voltage	V_{SD}	-	0.75	1	V	$V_{GS} = 0V$, $I_S = 1A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C _{iss}	-	2370	-	pF	., .=,,,,	
Output Capacitance	Coss	-	1360	-	pF	$V_{DS} = 15V, V_{GS} = 0V,$ -f = 1MHz	
Reverse Transfer Capacitance	Crss	-	240	-	pF		
Gate Resistance	Rg	-	0.6	-	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	-	20	-	nC		
Total Gate Charge (V _{GS} = 10V)	Qg	-	44	-	nC	V 45V L 20A	
Gate-Source Charge	Q _{gs}	-	7	-	nC	$V_{DS} = 15V, I_{D} = 20A$	
Gate-Drain Charge	Q _{gd}	-	8	-	nC	7	
Turn-On Delay Time	t _{D(ON)}	-	6.2	-	ns		
Turn-On Rise Time	t _R	-	4.3	-	ns	V _{DD} = 15V, V _{GS} = 10V,	
Turn-Off Delay Time	t _{D(OFF)}	-	21	-	ns	$R_L = 0.75\Omega$, $R_G = 3\Omega$, $I_D = 20A$	
Turn-Off Fall Time	t _F	-	8	-	ns	7	
Reverse Recovery Time	t _{RR}	=	25	-	ns	1 15A di/dt 500A/vo	
Reverse Recovery Charge	Q_{RR}	-	37	-	nC	I _F =15A, di/dt=500A/μs	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
- 7. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_{J} = +25°C.
- 8. Short duration pulse test used to minimize self-heating effect.
- 9. Guaranteed by design. Not subject to product testing.







Gate Voltage

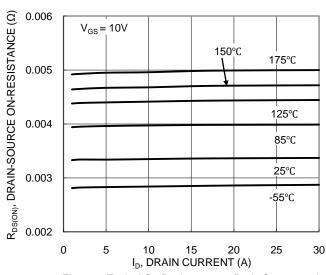
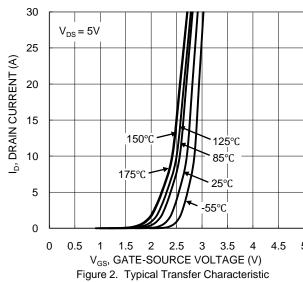
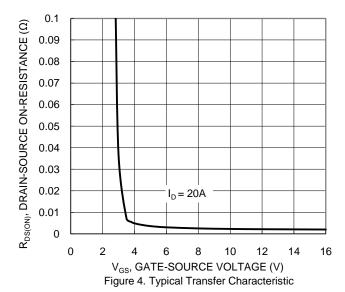
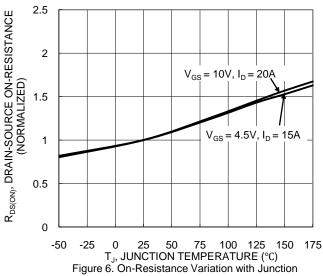


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature







Temperature



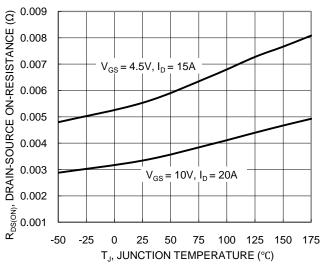


Figure 7. On-Resistance Variation with Junction Temperature

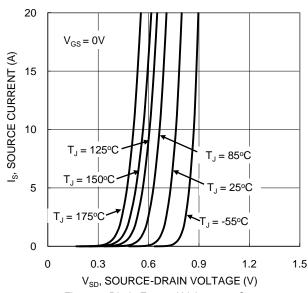
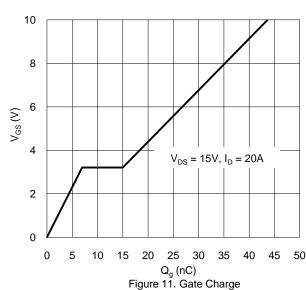


Figure 9. Diode Forward Voltage vs. Current



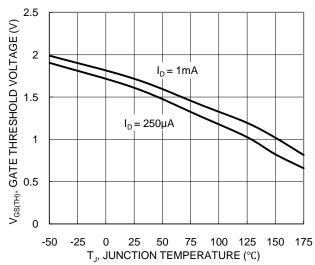
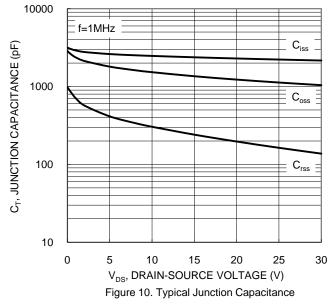
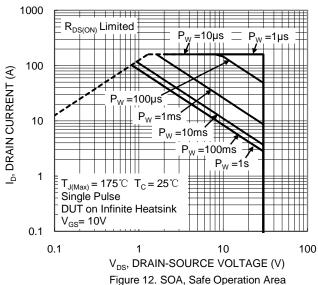
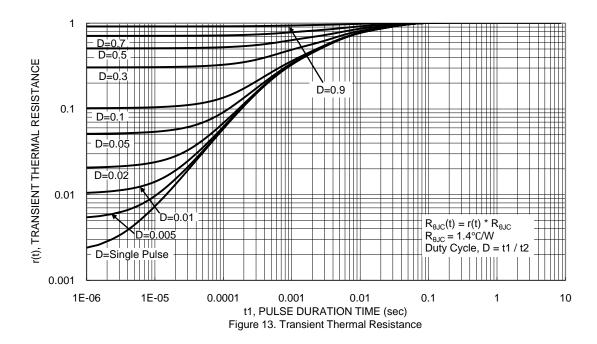


Figure 8. Gate Threshold Variation vs. Junction Temperature



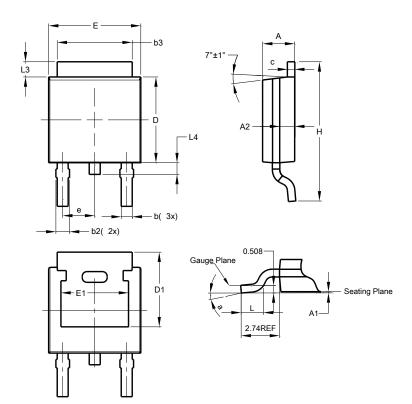






Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

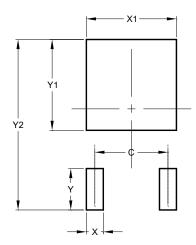


TO252 (DPAK)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
C	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	-	-		
е	-	-	2.286		
Е	6.45	6.70	6.58		
E1	4.32	-	-		
Н	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	-		
All Dimensions in mm					



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)			
С	4.572			
X	1.060			
X1	5.632			
Y	2.600			
Y1	5.700			
Y2	10.700			

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